

**MOTOROLA**  
SEMICONDUCTOR TECHNICAL DATA

## 8-Bit Serial-Input/Serial or Parallel-Output Shift Register with Latched 3-State Outputs High-Performance Silicon-Gate CMOS

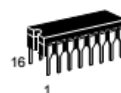
The MC54/74HC595A is identical in pinout to the LS595. The device inputs are compatible with standard CMOS outputs; with pullup resistors, they are compatible with LSTTL outputs.

The HC595A consists of an 8-bit shift register and an 8-bit D-type latch with three-state parallel outputs. The shift register accepts serial data and provides a serial output. The shift register also provides parallel data to the 8-bit latch. The shift register and latch have independent clock inputs. This device also has an asynchronous reset for the shift register.

The HC595A directly interfaces with the Motorola SPI serial data port on CMOS MPUs and MCUs.

- Output Drive Capability: 15 LSTTL Loads
- Outputs Directly Interface to CMOS, NMOS, and TTL
- Operating Voltage Range: 2.0 to 6.0 V
- Low Input Current: 1.0  $\mu$ A
- High Noise Immunity Characteristic of CMOS Devices
- In Compliance with the Requirements Defined by JEDEC Standard No. 7A
- Chip Complexity: 328 FETs or 82 Equivalent Gates
- Improvements over HC595
  - Improved Propagation Delays
  - 50% Lower Quiescent Power
  - Improved Input Noise and Latchup Immunity

### MC54/74HC595A



**J SUFFIX**  
CERAMIC PACKAGE  
CASE 620-10



**N SUFFIX**  
PLASTIC PACKAGE  
CASE 648-08



**D SUFFIX**  
SOIC PACKAGE  
CASE 751B-05

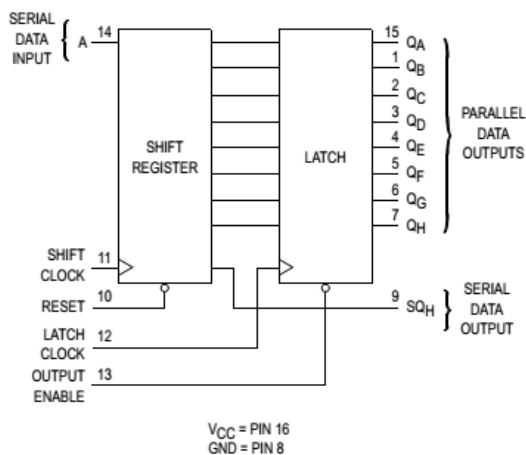


**DT SUFFIX**  
TSSOP PACKAGE  
CASE 948F-01

#### ORDERING INFORMATION

MC54HCXXXAJ	Ceramic
MC74HCXXXAN	Plastic
MC74HCXXXAD	SOIC
MC74HCXXXADT	TSSOP

#### LOGIC DIAGRAM



#### PIN ASSIGNMENT

QB	1	16	V <sub>CC</sub>
QC	2	15	Q <sub>A</sub>
QD	3	14	A
QE	4	13	OUTPUT ENABLE
QF	5	12	LATCH CLOCK
QG	6	11	SHIFT CLOCK
QH	7	10	RESET
GND	8	9	SQ <sub>H</sub>



## MC54/74HC595A

## MAXIMUM RATINGS\*

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	DC Supply Voltage (Referenced to GND)	- 0.5 to + 7.0	V
V <sub>in</sub>	DC Input Voltage (Referenced to GND)	- 1.5 to V <sub>CC</sub> + 1.5	V
V <sub>out</sub>	DC Output Voltage (Referenced to GND)	- 0.5 to V <sub>CC</sub> + 0.5	V
I <sub>in</sub>	DC Input Current, per Pin	± 20	mA
I <sub>out</sub>	DC Output Current, per Pin	± 35	mA
I <sub>CC</sub>	DC Supply Current, V <sub>CC</sub> and GND Pins	± 75	mA
P <sub>D</sub>	Power Dissipation in Still Air, Plastic or Ceramic DIP† SOIC Package† TSSOP Package†	750 500 450	mW
T <sub>stg</sub>	Storage Temperature	- 65 to + 150	°C
T <sub>L</sub>	Lead Temperature, 1 mm from Case for 10 Seconds (Plastic DIP, SOIC or TSSOP Package) (Ceramic DIP)	260 300	°C

\* Maximum Ratings are those values beyond which damage to the device may occur. Functional operation should be restricted to the Recommended Operating Conditions.

† Derating — Plastic DIP: - 10 mW/°C from 65° to 125°C  
Ceramic DIP: - 10 mW/°C from 100° to 125°C  
SOIC Package: - 7 mW/°C from 65° to 125°C  
TSSOP Package: - 6.1 mW/°C from 65° to 125°C

For high frequency or heavy load considerations, see Chapter 2 of the Motorola High-Speed CMOS Data Book (DL129/D).

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V<sub>in</sub> and V<sub>out</sub> should be constrained to the range GND ≤ (V<sub>in</sub> or V<sub>out</sub>) ≤ V<sub>CC</sub>. Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V<sub>CC</sub>). Unused outputs must be left open.

## RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V <sub>CC</sub>	DC Supply Voltage (Referenced to GND)	2.0	6.0	V
V <sub>in</sub> , V <sub>out</sub>	DC Input Voltage, Output Voltage (Referenced to GND)	0	V <sub>CC</sub>	V
T <sub>A</sub>	Operating Temperature, All Package Types	- 55	+ 125	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Time (Figure 1)	V <sub>CC</sub> = 2.0 V 0 V <sub>CC</sub> = 4.5 V 0 V <sub>CC</sub> = 6.0 V	1000 500 400	ns

## DC ELECTRICAL CHARACTERISTICS (Voltages Referenced to GND)

Symbol	Parameter	Test Conditions	V <sub>CC</sub> V	Guaranteed Limit			Unit
				- 55 to 25°C	≤ 85°C	≤ 125°C	
V <sub>IH</sub>	Minimum High-Level Input Voltage	V <sub>out</sub> = 0.1 V or V <sub>CC</sub> - 0.1 V  I <sub>out</sub>   ≤ 20 μA	2.0	1.5	1.5	1.5	V
			4.5	3.15	3.15	3.15	
			6.0	4.2	4.2	4.2	
V <sub>IL</sub>	Maximum Low-Level Input Voltage	V <sub>out</sub> = 0.1 V or V <sub>CC</sub> - 0.1 V  I <sub>out</sub>   ≤ 20 μA	2.0	0.5	0.5	0.5	V
			4.5	1.35	1.35	1.35	
			6.0	1.8	1.8	1.8	
V <sub>OH</sub>	Minimum High-Level Output Voltage, Q <sub>A</sub> - Q <sub>H</sub>	V <sub>in</sub> = V <sub>IH</sub> or V <sub>IL</sub>  I <sub>out</sub>   ≤ 20 μA	2.0	1.9	1.9	1.9	V
			4.5	4.4	4.4	4.4	
			6.0	5.9	5.9	5.9	
			V <sub>in</sub> = V <sub>IH</sub> or V <sub>IL</sub>  I <sub>out</sub>   ≤ 6.0 mA  I <sub>out</sub>   ≤ 7.8 mA	4.5	3.98	3.84	
6.0	5.48	5.34	5.2				
V <sub>OL</sub>	Maximum Low-Level Output Voltage, Q <sub>A</sub> - Q <sub>H</sub>	V <sub>in</sub> = V <sub>IH</sub> or V <sub>IL</sub>  I <sub>out</sub>   ≤ 20 μA	2.0	0.1	0.1	0.1	V
			4.5	0.1	0.1	0.1	
			6.0	0.1	0.1	0.1	
			V <sub>in</sub> = V <sub>IH</sub> or V <sub>IL</sub>  I <sub>out</sub>   ≤ 6.0 mA  I <sub>out</sub>   ≤ 7.8 mA	4.5	0.26	0.33	
6.0	0.26	0.33	0.4				

NOTE: Information on typical parametric values can be found in Chapter 2 of the Motorola High-Speed CMOS Data Book (DL129/D).

## MC54/74HC595A

## DC ELECTRICAL CHARACTERISTICS (Continued)

Symbol	Parameter	Test Conditions	V <sub>CC</sub> V	Guaranteed Limit			Unit
				- 55 to 25 °C	≤ 85 °C	≤ 125 °C	
V <sub>OH</sub>	Minimum High-Level Output Voltage, SQ <sub>H</sub>	V <sub>in</sub> = V <sub>IH</sub> or V <sub>IL</sub>  I <sub>out</sub>   ≤ 20 μA	2.0	1.9	1.9	1.9	V
			4.5	4.4	4.4	4.4	
			6.0	5.9	5.9	5.9	
		V <sub>in</sub> = V <sub>IH</sub> or V <sub>IL</sub>  I <sub>out</sub>   ≤ 4.0 mA  I <sub>out</sub>   ≤ 5.2 mA	4.5	3.98	3.84	3.7	
			6.0	5.48	5.34	5.2	
V <sub>OL</sub>	Maximum Low-Level Output Voltage, SQ <sub>H</sub>	V <sub>in</sub> = V <sub>IH</sub> or V <sub>IL</sub>  I <sub>out</sub>   ≤ 20 μA	2.0	0.1	0.1	0.1	V
			4.5	0.1	0.1	0.1	
			6.0	0.1	0.1	0.1	
		V <sub>in</sub> = V <sub>IH</sub> or V <sub>IL</sub>  I <sub>out</sub>   ≤ 4.0 mA  I <sub>out</sub>   ≤ 5.2 mA	4.5	0.26	0.33	0.4	
			6.0	0.26	0.33	0.4	
I <sub>in</sub>	Maximum Input Leakage Current	V <sub>in</sub> = V <sub>CC</sub> or GND	6.0	± 0.1	± 1.0	± 1.0	μA
I <sub>OZ</sub>	Maximum Three-State Leakage Current, Q <sub>A</sub> - Q <sub>H</sub>	Output in High-Impedance State V <sub>in</sub> = V <sub>IL</sub> or V <sub>IH</sub> V <sub>out</sub> = V <sub>CC</sub> or GND	6.0	± 0.5	± 5.0	± 10	μA
I <sub>CC</sub>	Maximum Quiescent Supply Current (per Package)	V <sub>in</sub> = V <sub>CC</sub> or GND I <sub>out</sub> = 0 μA	6.0	4.0	40	160	μA

AC ELECTRICAL CHARACTERISTICS (C<sub>L</sub> = 50 pF, Input t<sub>r</sub> = t<sub>f</sub> = 6.0 ns)

Symbol	Parameter	V <sub>CC</sub> V	Guaranteed Limit			Unit
			- 55 to 25 °C	≤ 85 °C	≤ 125 °C	
f <sub>max</sub>	Maximum Clock Frequency (50% Duty Cycle) (Figures 1 and 7)	2.0	6.0	4.8	4.0	MHz
		4.5	30	24	20	
		6.0	35	28	24	
t <sub>PLH</sub> , t <sub>PHL</sub>	Maximum Propagation Delay, Shift Clock to SQ <sub>H</sub> (Figures 1 and 7)	2.0	140	175	210	ns
		4.5	28	35	42	
		6.0	24	30	36	
t <sub>PHL</sub>	Maximum Propagation Delay, Reset to SQ <sub>H</sub> (Figures 2 and 7)	2.0	145	180	220	ns
		4.5	29	36	44	
		6.0	25	31	38	
t <sub>PLH</sub> , t <sub>PHL</sub>	Maximum Propagation Delay, Latch Clock to Q <sub>A</sub> - Q <sub>H</sub> (Figures 3 and 7)	2.0	140	175	210	ns
		4.5	28	35	42	
		6.0	24	30	36	
t <sub>PLZ</sub> , t <sub>PHZ</sub>	Maximum Propagation Delay, Output Enable to Q <sub>A</sub> - Q <sub>H</sub> (Figures 4 and 8)	2.0	150	190	225	ns
		4.5	30	38	45	
		6.0	26	33	38	
t <sub>PZL</sub> , t <sub>PZH</sub>	Maximum Propagation Delay, Output Enable to Q <sub>A</sub> - Q <sub>H</sub> (Figures 4 and 8)	2.0	135	170	205	ns
		4.5	27	34	41	
		6.0	23	29	35	
t <sub>TLH</sub> , t <sub>THL</sub>	Maximum Output Transition Time, Q <sub>A</sub> - Q <sub>H</sub> (Figures 3 and 7)	2.0	60	75	90	ns
		4.5	12	15	18	
		6.0	10	13	15	
t <sub>TLH</sub> , t <sub>THL</sub>	Maximum Output Transition Time, SQ <sub>H</sub> (Figures 1 and 7)	2.0	75	95	110	ns
		4.5	15	19	22	
		6.0	13	16	19	
C <sub>in</sub>	Maximum Input Capacitance	—	10	10	10	pF
C <sub>out</sub>	Maximum Three-State Output Capacitance (Output in High-Impedance State), Q <sub>A</sub> - Q <sub>H</sub>	—	15	15	15	pF

NOTE: For propagation delays with loads other than 50 pF, and information on typical parametric values, see Chapter 2 of the Motorola High-Speed CMOS Data Book (DL129/D).

C <sub>PD</sub>	Power Dissipation Capacitance (Per Package)*	Typical @ 25°C, V <sub>CC</sub> = 5.0 V	
		300	pF

\* Used to determine the no-load dynamic power consumption: P<sub>D</sub> = C<sub>PD</sub> V<sub>CC</sub><sup>2</sup>f + I<sub>CC</sub> V<sub>CC</sub>. For load considerations, see Chapter 2 of the Motorola High-Speed CMOS Data Book (DL129/D).

## MC54/74HC595A

TIMING REQUIREMENTS (Input  $t_r = t_f = 6.0$  ns)

Symbol	Parameter	V <sub>CC</sub> V	Guaranteed Limit			Unit
			25°C to -55°C	≤ 85°C	≤ 125°C	
$t_{su}$	Minimum Setup Time, Serial Data Input A to Shift Clock (Figure 5)	2.0 4.5 6.0	50 10 9.0	65 13 11	75 15 13	ns
$t_{su}$	Minimum Setup Time, Shift Clock to Latch Clock (Figure 6)	2.0 4.5 6.0	75 15 13	95 19 16	110 22 19	ns
$t_h$	Minimum Hold Time, Shift Clock to Serial Data Input A (Figure 5)	2.0 4.5 6.0	5.0 5.0 5.0	5.0 5.0 5.0	5.0 5.0 5.0	ns
$t_{rec}$	Minimum Recovery Time, Reset Inactive to Shift Clock (Figure 2)	2.0 4.5 6.0	50 10 9.0	65 13 11	75 15 13	ns
$t_w$	Minimum Pulse Width, Reset (Figure 2)	2.0 4.5 6.0	60 12 10	75 15 13	90 18 15	ns
$t_w$	Minimum Pulse Width, Shift Clock (Figure 1)	2.0 4.5 6.0	50 10 9.0	65 13 11	75 15 13	ns
$t_w$	Minimum Pulse Width, Latch Clock (Figure 6)	2.0 4.5 6.0	50 10 9.0	65 13 11	75 15 13	ns
$t_r, t_f$	Maximum Input Rise and Fall Times (Figure 1)	2.0 4.5 6.0	1000 500 400	1000 500 400	1000 500 400	ns

## FUNCTION TABLE

Operation	Inputs					Resulting Function			
	Reset	Serial Input A	Shift Clock	Latch Clock	Output Enable	Shift Register Contents	Latch Register Contents	Serial Output SQ <sub>H</sub>	Parallel Outputs Q <sub>A</sub> - Q <sub>H</sub>
Reset shift register	L	X	X	L, H, $\sim$	L	L	U	L	U
Shift data into shift register	H	D	$\sim$	L, H, $\sim$	L	D → SR <sub>A</sub> ; SR <sub>N</sub> → SR <sub>N+1</sub>	U	SR <sub>G</sub> → SR <sub>H</sub>	U
Shift register remains unchanged	H	X	L, H, $\sim$	L, H, $\sim$	L	U	U	U	U
Transfer shift register contents to latch register	H	X	L, H, $\sim$	$\sim$	L	U	SR <sub>N</sub> → LR <sub>N</sub>	U	SR <sub>N</sub>
Latch register remains unchanged	X	X	X	L, H, $\sim$	L	*	U	*	U
Enable parallel outputs	X	X	X	X	L	*	**	*	Enabled
Force outputs into high impedance state	X	X	X	X	H	*	**	*	Z

SR = shift register contents  
LR = latch register contents

D = data (L, H) logic level  
U = remains unchanged

X = don't care  
Z = high impedance

\* = depends on Reset and Shift Clock inputs  
\*\* = depends on Latch Clock input

## MC54/74HC595A

## PIN DESCRIPTIONS

## INPUTS

**A (Pin 14)**

Serial Data Input. The data on this pin is shifted into the 8-bit serial shift register.

## CONTROL INPUTS

**Shift Clock (Pin 11)**

Shift Register Clock Input. A low-to-high transition on this input causes the data at the Serial Input pin to be shifted into the 8-bit shift register.

**Reset (Pin 10)**

Active-low, Asynchronous, Shift Register Reset Input. A low on this pin resets the shift register portion of this device only. The 8-bit latch is not affected.

**Latch Clock (Pin 12)**

Storage Latch Clock Input. A low-to-high transition on this input latches the shift register data.

**Output Enable (Pin 13)**

Active-low Output Enable. A low on this input allows the data from the latches to be presented at the outputs. A high on this input forces the outputs (QA-QH) into the high-impedance state. The serial output is not affected by this control unit.

## OUTPUTS

**QA – QH (Pins 15, 1, 2, 3, 4, 5, 6, 7)**

Noninverted, 3-state, latch outputs.

**SQH (Pin 9)**

Noninverted, Serial Data Output. This is the output of the eighth stage of the 8-bit shift register. This output does not have three-state capability.

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MC54/74HC595A

SWITCHING WAVEFORMS

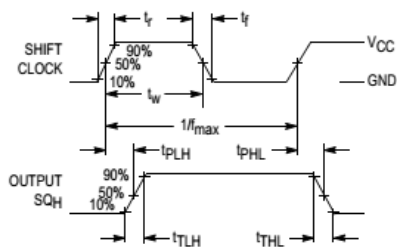


Figure 1.

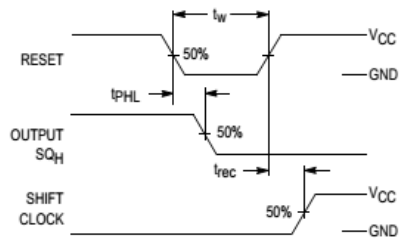


Figure 2.

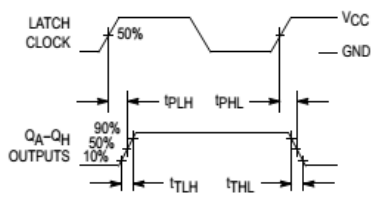


Figure 3.

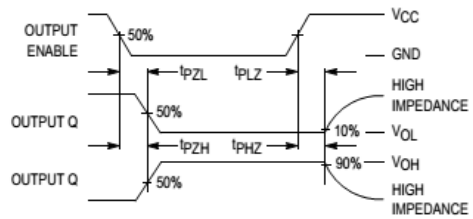


Figure 4.

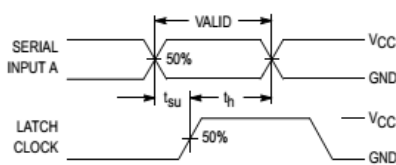


Figure 5.

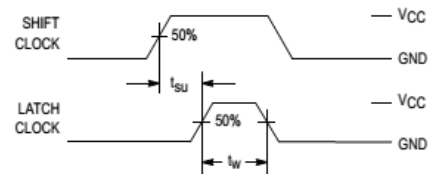
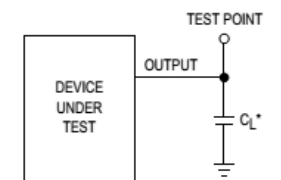


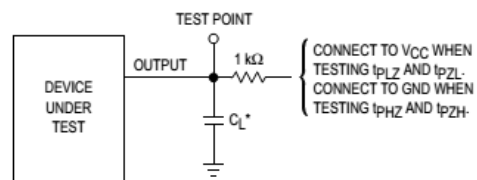
Figure 6.

TEST CIRCUITS



\* Includes all probe and jig capacitance

Figure 7.

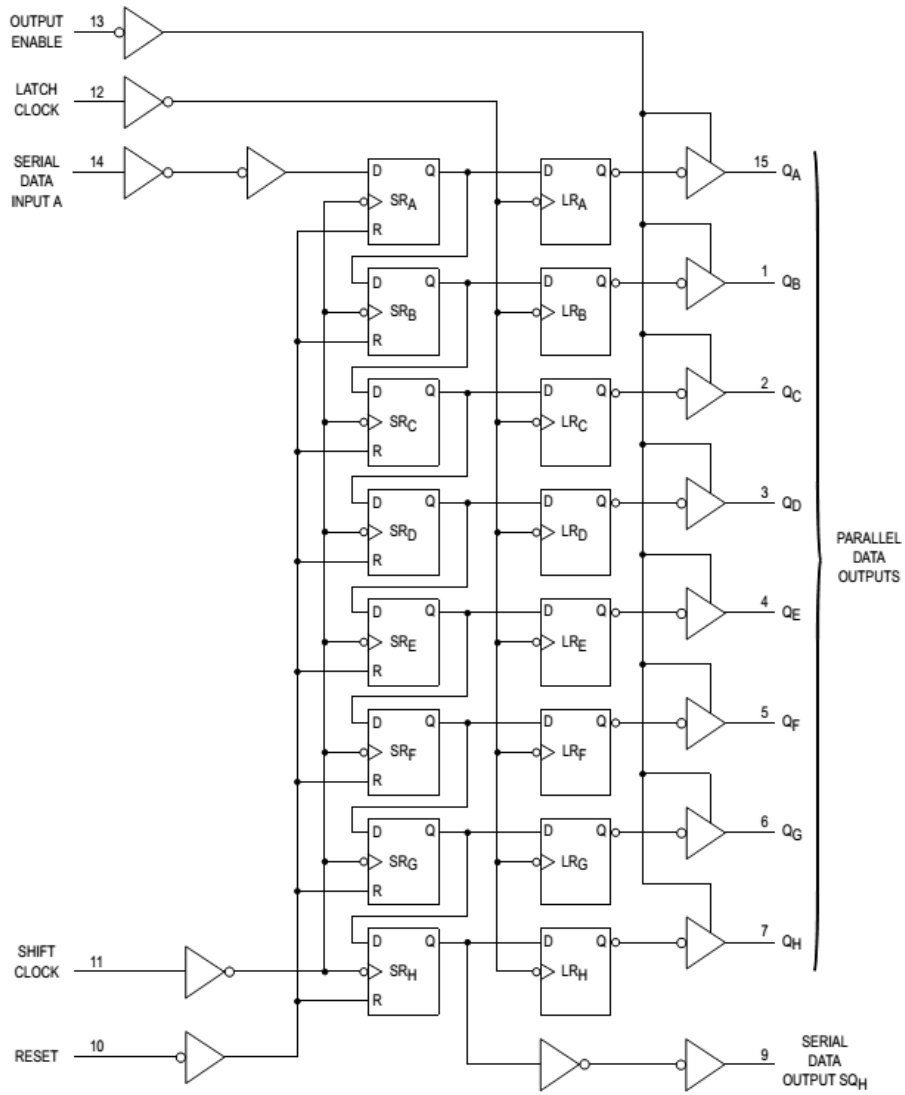


\* Includes all probe and jig capacitance

Figure 8.

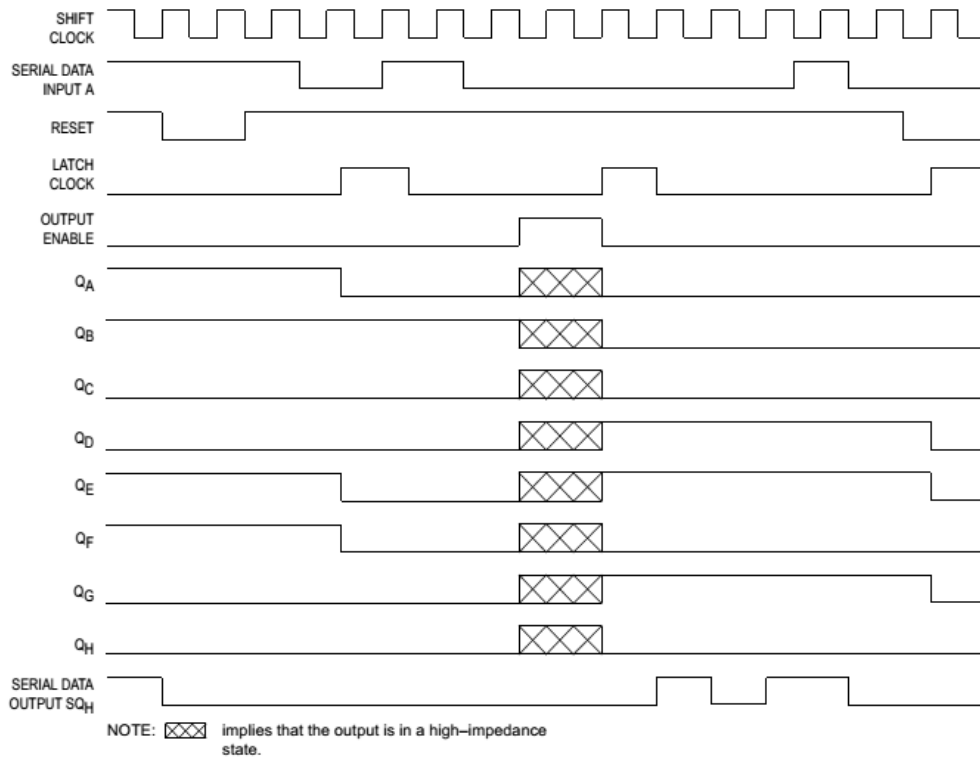
MC54/74HC595A

EXPANDED LOGIC DIAGRAM



## MC54/74HC595A

## TIMING DIAGRAM

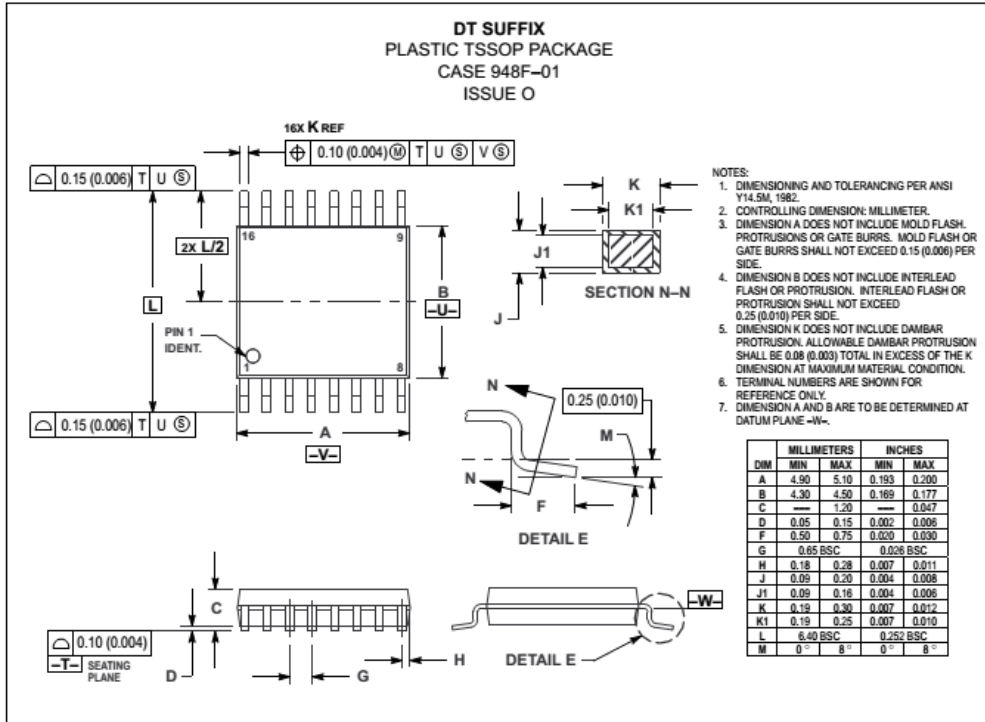






MC54/74HC595A

OUTLINE DIMENSIONS



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COE LINE

MC54/74HC595A/D





## ULN2001A-ULN2002A ULN2003A-ULN2004A

### SEVEN DARLINGTON ARRAYS

- SEVEN DARLINGTONS PER PACKAGE
- OUTPUT CURRENT 500mA PER DRIVER (600mA PEAK)
- OUTPUT VOLTAGE 50V
- INTEGRATED SUPPRESSION DIODES FOR INDUCTIVE LOADS
- OUTPUTS CAN BE PARALLELED FOR HIGHER CURRENT
- TTL/CMOS/PMOS/DTL COMPATIBLE INPUTS
- INPUTS PINNED OPPOSITE OUTPUTS TO SIMPLIFY LAYOUT

#### DESCRIPTION

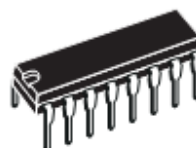
The ULN2001A, ULN2002A, ULN2003 and ULN2004A are high voltage, high current darlington arrays each containing seven open collector darlington pairs with common emitters. Each channel rated at 500mA and can withstand peak currents of 600mA. Suppression diodes are included for inductive load driving and the inputs are pinned opposite the outputs to simplify board layout.

The four versions interface to all common logic families :

ULN2001A	General Purpose, DTL, TTL, PMOS, CMOS
ULN2002A	14-25V PMOS
ULN2003A	5V TTL, CMOS
ULN2004A	6-15V CMOS, PMOS

These versatile devices are useful for driving a wide range of loads including solenoids, relays DC motors, LED displays filament lamps, thermal print-heads and high power buffers.

The ULN2001A/2002A/2003A and 2004A are supplied in 16 pin plastic DIP packages with a copper leadframe to reduce thermal resistance. They are available also in small outline package (SO-16) as ULN2001D/2002D/2003D/2004D.



DIP16

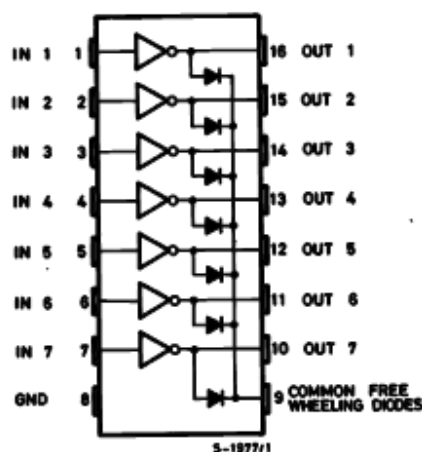
ORDERING NUMBERS: ULN2001A/2A/3A/4A



SO16

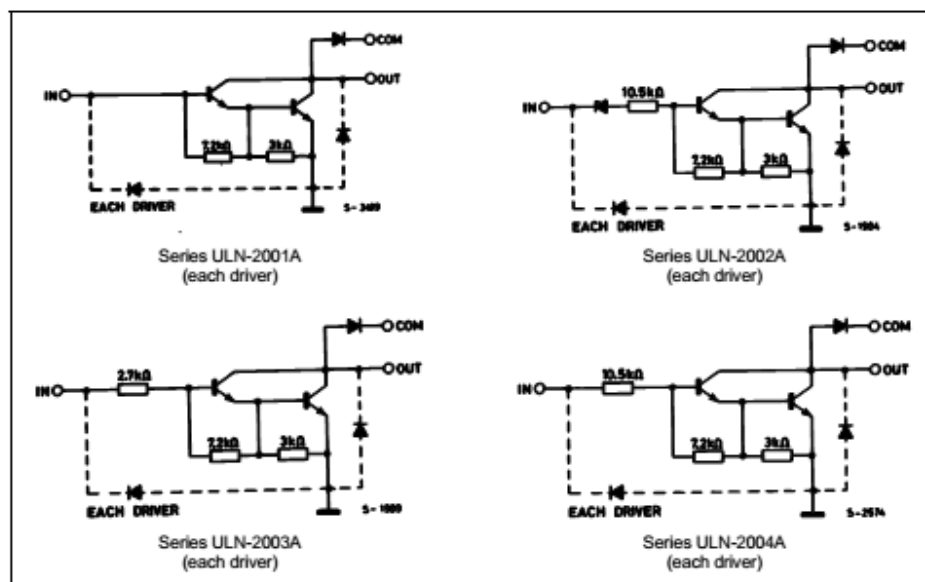
ORDERING NUMBERS: ULN2001D/2D/3D/4D

#### PIN CONNECTION



## ULN2001A - ULN2002A - ULN2003A - ULN2004A

## SCHEMATIC DIAGRAM



## ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
$V_o$	Output Voltage	50	V
$V_{in}$	Input Voltage (for ULN2002A/D - 2003A/D - 2004A/D)	30	V
$I_c$	Continuous Collector Current	500	mA
$I_b$	Continuous Base Current	25	mA
$T_{amb}$	Operating Ambient Temperature Range	- 20 to 85	°C
$T_{stg}$	Storage Temperature Range	- 55 to 150	°C
$T_j$	Junction Temperature	150	°C

## THERMAL DATA

Symbol	Parameter	DIP16	SO16	Unit
$R_{th\ j-amb}$	Thermal Resistance Junction-ambient	Max. 70	120	°C/W

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**ULN2001A - ULN2002A - ULN2003A - ULN2004A**


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**ELECTRICAL CHARACTERISTICS** ( $T_{amb} = 25^{\circ}\text{C}$  unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit	Fig.
$I_{CEX}$	Output Leakage Current	$V_{CE} = 50\text{V}$ $T_{amb} = 70^{\circ}\text{C}$ , $V_{CE} = 50\text{V}$			50 100	$\mu\text{A}$ $\mu\text{A}$	1a 1a
		$T_{amb} = 70^{\circ}\text{C}$ for ULN2002A $V_{CE} = 50\text{V}$ , $V_i = 6\text{V}$			500	$\mu\text{A}$	1b
		for ULN2004A $V_{CE} = 50\text{V}$ , $V_i = 1\text{V}$			500	$\mu\text{A}$	1b
$V_{CE(sat)}$	Collector-emitter Saturation Voltage	$I_C = 100\text{mA}$ , $I_B = 250\mu\text{A}$		0.9	1.1	V	2
		$I_C = 200\text{mA}$ , $I_B = 350\mu\text{A}$		1.1	1.3	V	2
		$I_C = 350\text{mA}$ , $I_B = 500\mu\text{A}$		1.3	1.6	V	2
$I_{(on)}$	Input Current	for ULN2002A, $V_i = 17\text{V}$		0.82	1.25	mA	3
		for ULN2003A, $V_i = 3.85\text{V}$		0.93	1.35	mA	3
		for ULN2004A, $V_i = 5\text{V}$		0.35	0.5	mA	3
		$V_i = 12\text{V}$		1	1.45	mA	3
$I_{(off)}$	Input Current	$T_{amb} = 70^{\circ}\text{C}$ , $I_C = 500\mu\text{A}$	50	65		$\mu\text{A}$	4
$V_{(on)}$	Input Voltage	$V_{CE} = 2\text{V}$ for ULN2002A $I_C = 300\text{mA}$			13	V	5
		for ULN2003A $I_C = 200\text{mA}$			2.4		
		$I_C = 250\text{mA}$			2.7		
		$I_C = 300\text{mA}$			3		
		for ULN2004A $I_C = 125\text{mA}$			5		
		$I_C = 200\text{mA}$			6		
		$I_C = 275\text{mA}$			7		
		$I_C = 350\text{mA}$			8		
$h_{FE}$	DC Forward Current Gain	for ULN2001A $V_{CE} = 2\text{V}$ , $I_C = 350\text{mA}$	1000				2
$C_i$	Input Capacitance			15	25	pF	
$t_{PLH}$	Turn-on Delay Time	$0.5 V_i$ to $0.5 V_o$		0.25	1	$\mu\text{s}$	
$t_{PHL}$	Turn-off Delay Time	$0.5 V_i$ to $0.5 V_o$		0.25	1	$\mu\text{s}$	
$I_R$	Clamp Diode Leakage Current	$V_R = 50\text{V}$			50	$\mu\text{A}$	6
		$T_{amb} = 70^{\circ}\text{C}$ , $V_R = 50\text{V}$			100	$\mu\text{A}$	6
$V_F$	Clamp Diode Forward Voltage	$I_F = 350\text{mA}$		1.7	2	V	7

ULN2001A - ULN2002A - ULN2003A - ULN2004A

TEST CIRCUITS

Figure 1a.

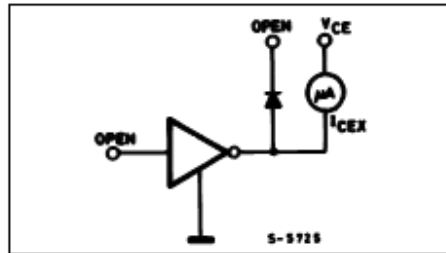


Figure 1b.

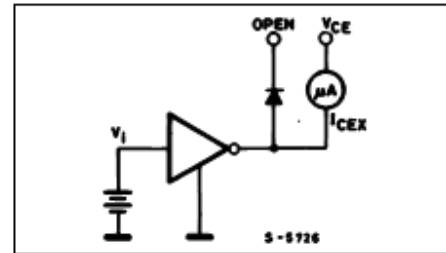


Figure 2.

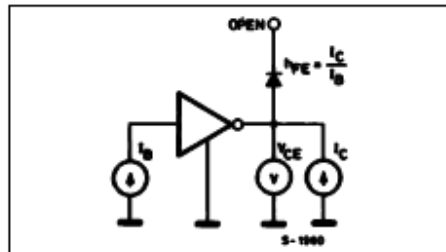


Figure 3.

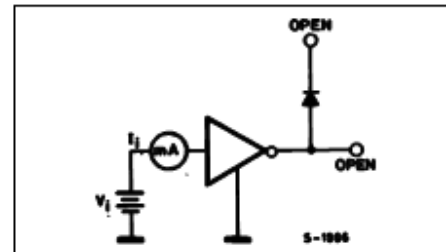


Figure 4.

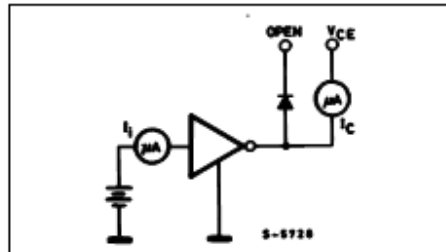


Figure 5.

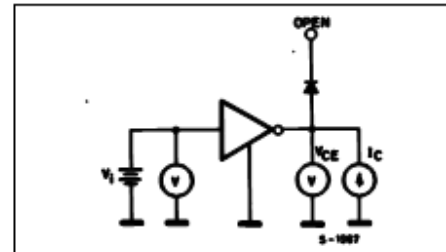


Figure 6.

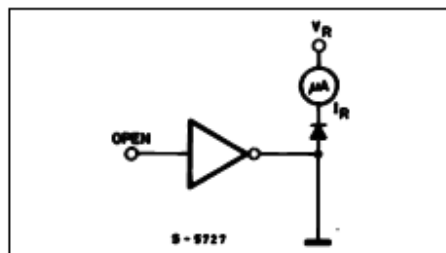
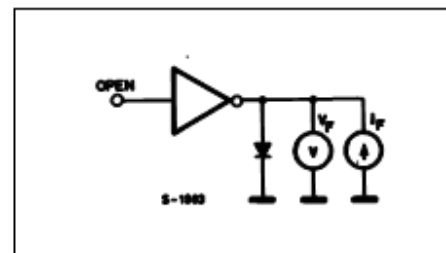


Figure 7.



ULN2001A - ULN2002A - ULN2003A - ULN2004A

Figure 8: Collector Current versus Input Current

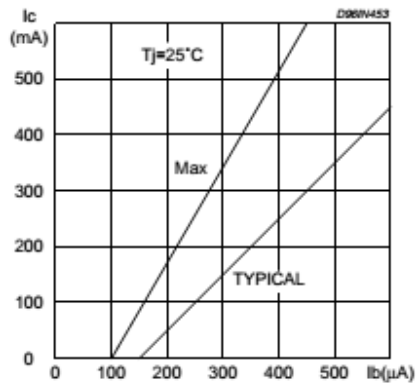


Figure 9: Collector Current versus Saturation Voltage

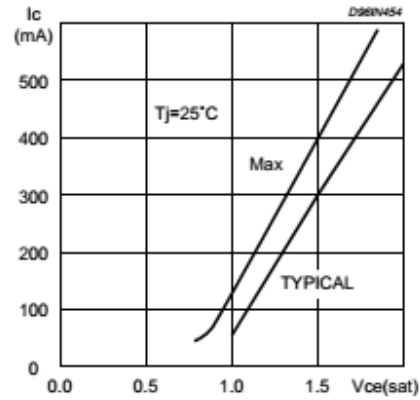


Figure 10: Peak Collector Current versus Duty Cycle

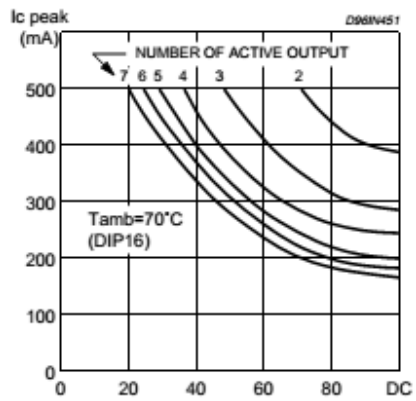
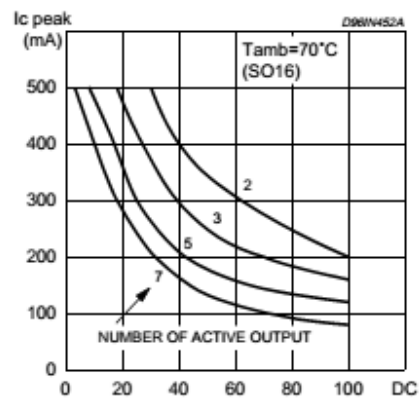
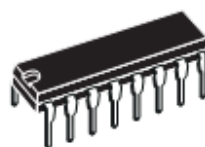


Figure 11: Peak Collector Current versus Duty Cycle

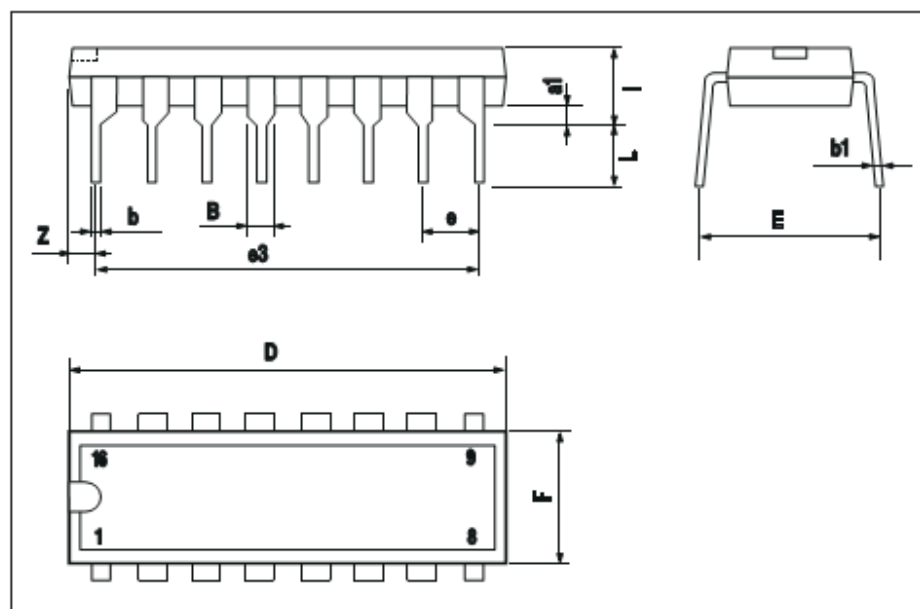


## ULN2001A - ULN2002A - ULN2003A - ULN2004A

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
a1	0.51			0.020		
B	0.77		1.65	0.030		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e3		17.78			0.700	
F			7.1			0.280
I			5.1			0.201
L		3.3			0.130	
Z			1.27			0.050

OUTLINE AND  
MECHANICAL DATA

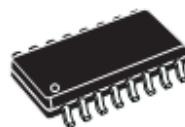
DIP16





## ULN2001A - ULN2002A - ULN2003A - ULN2004A

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			1.75			0.069
a1	0.1		0.25	0.004		0.009
a2			1.6			0.063
b	0.35		0.46	0.014		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.020	
c1	45° (typ.)					
D (1)	9.8		10	0.386		0.394
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		8.89			0.350	
F (1)	3.8		4	0.150		0.157
G	4.6		5.3	0.181		0.209
L	0.4		1.27	0.016		0.050
M			0.62			0.024
S	8° (max.)					

OUTLINE AND  
MECHANICAL DATA

## SO16 Narrow

(1) D and F do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15mm (.005inch).

